TOSHIBA Transistor Silicon NPN Epitaxial Type

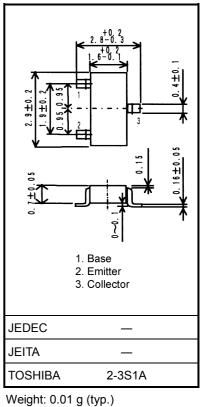
2SC5738

High-Speed Switching Applications DC-DC Converter Applications

- High DC current gain: $h_{FE} = 400$ to 1000 (I_C = 0.5 A)
- Low collector-emitter saturation voltage: V_{CE} (sat) = 0.15 V (max)
- High-speed switching: $t_f = 90 \text{ ns}$ (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	40	V	
Collector-emitter voltage		V _{CEX}	30	V	
Collector-emitter voltage		V _{CEO}	20	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	Ι _C	3.5	A	
	Pulse	I _{CP}	6.0		
Base current		Ι _Β	350	mA	
Collector power dissipation	DC	P _C	625	mW	
	t = 10 s	(Note)	1000		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



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Note: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)

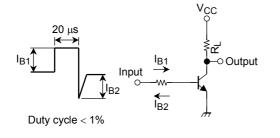
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	$V_{CB} = 40 \text{ V}, I_E = 0$			100	nA	
Emitter cut-off current		I _{EBO}	$V_{EB} = 7 V, I_C = 0$	_	_	100	nA	
Collector-emitter breakdown voltage		V (BR) CEO	$I_{C} = 10 \text{ mA}, I_{B} = 0$	20	_	_	V	
DC current gain		h _{FE} (1)	$V_{CE} = 2 V, I_C = 0.5 A$	400	_	1000		
		h _{FE} (2)	$V_{CE} = 2 V, I_C = 1.6 A$	200	_	_		
Collector-emitter saturation voltage		V _{CE (sat)}	$I_{C} = 1.6 \text{ A}, I_{B} = 32 \text{ mA}$			0.15	V	
Base-emitter saturation voltage		V _{BE (sat)}	$I_{C} = 1.6 \text{ A}, I_{B} = 32 \text{ mA}$	_	_	1.10	V	
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		18		pF	
Switching time	Rise time	tr	See Figure 1 circuit diagram.		100			
	Storage time	t _{stg}	$V_{CC} \simeq 12$ V, $R_L = 7.5 \Omega$		350		ns	
	Fall time	t _f	$I_{B1} = -I_{B2} = 53 \text{ mA}$		90			

Industrial Applications

Unit: mm

Marking



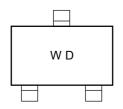
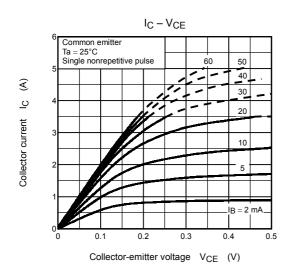
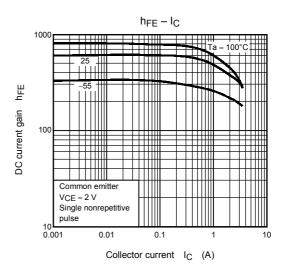
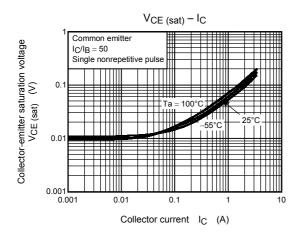


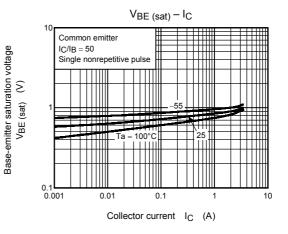
Figure 1 Switching Time Test Circuit & Timing Chart

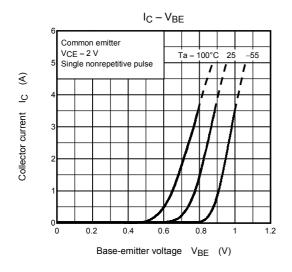
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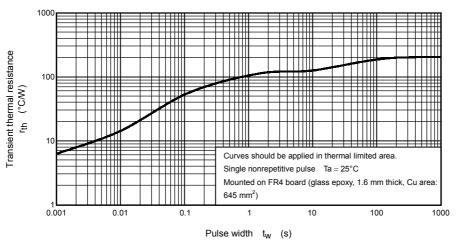












Transient Thermal Resistance rth - tw

Safe Operating Area 10 EIC max (pulsed) ♦ 0 μs• IC max (continuous) ______100 μs♦ _1 ms • _10 ms♦ € 100 ms 10 s♦* <u>ں</u> DC operation (Ta = 25°C) Collector current Contract State C 0.1 max VCEO r increase in temperature. 0.01 0.1 10 100 Collector-emitter voltage V_{CE} (V)

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